







SN54HCT74, SN74HCT74 SCLS169G - DECEMBER 1982 - REVISED OCTOBER 2022

SNx4HCT74 Dual D-Type Positive-Edge-Triggered Flip-Flips With Clear and Preset

1 Features

- Operating voltage range of 4.5 V to 5.5 V
- Outputs can drive up to 10 LSTTL loads
- Low power consumption, 40-µA max I_{CC}
- Typical $t_{pd} = 17 \text{ ns}$
- ±4-mA output drive at 5 V
- Low input current of 1 µA max
- Inputs are TTL-voltage compatible

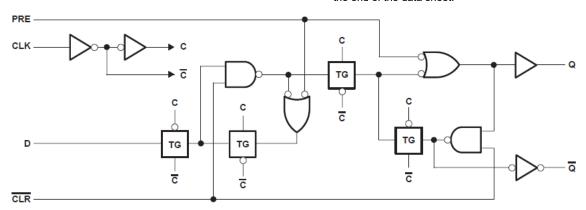
2 Description

The 'HCT74 devices contain two independent D-type positive-edge-triggered flip-flops. A low level at the preset (PRE) or clear (CLR) inputs sets or resets the outputs, regardless of the levels of the other inputs. When PRE and CLR are inactive (high), data at the data (D) input meeting the setup time requirements are transferred to the outputs on the positive-going edge of the clock (CLK) pulse. Clock triggering occurs at a voltage level and is not directly related to the rise time of CLK. Following the hold-time interval, data at the D input may be changed without affecting the levels at the outputs.

Device Information

PART NUMBER	PACKAGE ⁽¹⁾	BODY SIZE (NOM)
SN74HCT74D	SOIC (14)	8.65 mm × 3.90 mm
SN74HCT74DB	SSOP (14)	6.20 mm × 5.30 mm
SN74HCT74N	PDIP (14)	19.31 mm × 6.35 mm
SN74HCT74NS	SO (14)	10.20 mm × 5.30 mm
SN74HCT74PW	TSSOP (14)	5.00 mm × 4.40 mm
SNJ54HCT74FK	LCCC (20)	8.89 mm × 8.45 mm
SNJ54HCT74W	CFP (14)	9.21 mm × 6.29 mm
SNJ54HCT74J	CDIP (14)	19.55 mm × 6.71 mm

For all available packages, see the orderable addendum at the end of the data sheet.



Functional Block Diagram



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3 Revision History

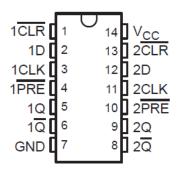
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision F (February 2022) to Revision G (October 2022) Changed PA IA for packages: D (86 to 138.7): N (80 to 61.1): NS (76 to 88.4): PW (113 to 114.7)

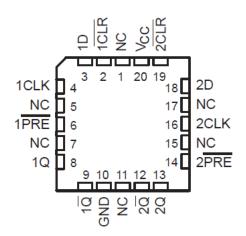
• Changed RθJA for packages: D (86 to 138.7); N (80 to 61.1); NS (76 to 88.4); PW (113 to 114.7)......4



4 Pin Configuration and Functions



J, W, D, DB, N, NS, or PW package 14-Pin CDIP, CFP, SOIC, SSOP, PDIP, SO, or TSSOP Top View



NC - No internal connection

FK Package 20-Pin LCCC Top View



5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1)

		<u> </u>	MIN	MAX	UNIT
V _{CC}	Supply voltage range	-0.5	7	V	
I _{IK}	Input clamp current ⁽²⁾	$V_I < 0$ or $V_I > V_{CC}$		± 20	mA
I _{OK}	Output clamp current ⁽²⁾	$V_O < 0$ or $V_O > V_{CC}$		± 20	mA
Io	Continuous output current	$V_O = 0$ to V_{CC}		± 25	mA
	Continuous current through V _{CC} or GND			± 50	mA
TJ	Junction temperature		150	°C	
T _{stg}	Storage temperature range		-65	150	°C

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

5.2 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			SN	54HCT74 ⁽²⁾		SN	74HCT74		UNIT
			MIN	NOM	MAX	MIN	NOM	MAX	UNIT
V _{CC}	Supply voltage		4.5	5	5.5	4.5	5	5.5	V
V _{IH}	High-level input voltage	V _{cc} = 4.5 V to 5.5 V	2			2			V
V _{IL}	Low-level input voltage	V _{cc} = 4.5 V to 5.5 V			0.8			0.8	V
VI	Input voltage		0		V _{CC}	0		V _{CC}	V
Vo	Output voltage	0		V _{CC}	0		V _{CC}	V	
Δt/Δν	Input transition rise/fall time			500			500	ns	
T _A	Operating free-air temperatu	ire	-55		125	-40		85	°C

⁽¹⁾ All unused inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

5.3 Thermal Information

		D (SOIC)	DB (SSOP)	N (PDIP)	NS (SO)	PW (TSSOP)	
THERMAL METRIC		14 PINS	14 PINS	14 PINS	14 PINS	14 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance ⁽¹⁾	138.7	109.8	61.1	88.4	114.7	°C/W
R _{θJC (top)}	Junction-to-case (top) thermal resistance	93.8	54.7	48.9	46	44.3	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	94.7	58.6	40.9	48.9	57.6	°C/W
Ψ_{JT}	Junction-to-top characterization parameter	49.1	15.5	28.5	13.8	4.8	°C/W
Ψ_{JB}	Junction-to-board characterization parameter	94.3	58	40.6	48.4	57	°C/W
R _{0JC (bot)}	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	N/A	N/A	°C/W

For more information about traditional and new thermal metrics, see the Semiconductor and IC package thermal metrics application report.

⁽²⁾ The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

⁽²⁾ SN54HCT74 is in product preview.



5.4 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CO	TEST CONDITIONS		Т	T _A = 25°C			SN54HCT74 ⁽²⁾		SN74HCT74	
PARAMETER	TEST CONDITIONS		V _{cc}	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
V _{OH}	\/. = \/ or \/	I _{OH} = -20 μA	4.5 V	4.4	4.499		4.4		4.4		V
VOH	$V_I = V_{IH}$ or V_{IL}	I _{OH} = -4 mA	4.5 V	3.98	4.3		3.7		3.84		v
V	\/ = \/ or \/	I _{OL} = 20 μA	4.5 V		0.001	0.1		0.1		0.1	V
V OL	V_{OL} $V_{I} = V_{IH} \text{ or } V_{IL}$	I _{OL} = 4 mA	4.5 V		0.17	0.26		0.4		0.33	
I _I	$V_I = V_{CC}$ or 0		5.5 V		±0.1	±100		±1000		±1000	nA
I _{cc}	$V_i = V_{CC}$ or 0,	I _O = 0	5.5 V			4		80		40	μA
ΔI _{CC} (1)	One input at 0.5 Other inputs at	·	5.5 V		1.4	2.4		3		2.9	mA
C _i			4.5 V to 5.5 V		3	10		10		10	pF

- (1) This is the increase in supply current for each input that is at one of the specified TTL voltage levels, rather than 0 V or V_{CC}.
- (2) SN54HCT74 is in product preview.

5.5 Timing Requirements

overrecommended operating free-air temperature range (unless otherwise noted)

			v	T _A = 2	5°C	SN54HC	T74 ⁽¹⁾	SN74HC	T74	UNIT
			V _{cc}	MIN	MAX	MIN	MAX	MIN	MAX	ONII
f	f _{clock} Clock frequency		4.5 V		27		18		22	MHz
f _{clock}	Clock frequency		5.5 V		30		20		24	IVII IZ
	t _w Pulse duration	PRE or CLR low	4.5 V	16		24		20		
		THE OF CERTION	5.5 V	14		21		18		- ns
w		CLK high or low	4.5 V	18		27		23		
			5.5 V	16		24		21		
		Data	4.5 V	12		18		15		- ns
	Setup time before CLK↑	Data	5.5 V	11		16		14		
t _{su}	Setup time before CLN	PRE or CLR inactive	4.5 V	0		0		0		
		PRE OF CLR Mactive	5.5 V	0		0		0		
	Hold time data after CLK		4.5 V	0		0		0		20
l'h	t _h Hold time, data after CLK↑			0		0		0		ns

(1) SN54HCT74 is in product preview.



5.6 Switching Characteristics

over recommended operating free-air temperature range, $C_L = 50 \text{ pF}$ (unless otherwise noted) (see Parameter Measurement Information)

PARAMETER	FROM	то	V	T _A = 25°C		SN54HCT74 ⁽¹⁾		SN74HCT74		UNIT	
PARAMETER	(INPUT)	(OUTPUT)	V _{cc}	MIN	TYP	MAX	MIN	MAX	MIN	MAX	ONIT
f			4.5 V	27	40		18		22		MHz
I max	f _{max}		5.5 V	30	46		20		24		IVITZ
	PRE or CLR	LR Q or Q	4.5 V		21	35		53		44	
	FRE OF CER		5.5 V		17	31		48		40	ns
t _{pd}	CLK	Q or $\overline{\mathbb{Q}}$	4.5 V		20	28		42		35	115
	CLK	QUIQ	5.5 V		18	25		38		31	
		Q or $\overline{\mathbb{Q}}$	4.5 V		8	15		22		19	no
t _t			5.5 V		7	14		20		17	ns

⁽¹⁾ SN54HCT74 is in product preview.

5.7 Operating Characteristics

T_A = 25°C

	PARAMETER	TEST CONDITIONS	TYP	UNIT
C _{pd}	Power dissipation capacitance per flip-flop	No load	35	pF

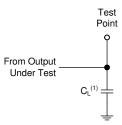


6 Parameter Measurement Information

Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , t_t < 6 ns.

For clock inputs, f_{max} is measured when the input duty cycle is 50%.

The outputs are measured one at a time with one input transition per measurement.



(1) C_L includes probe and test-fixture capacitance.

Figure 6-1. Load Circuit for Push-Pull Outputs

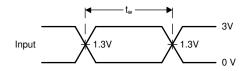


Figure 6-2. Voltage Waveforms, TTL-Compatible CMOS Inputs Pulse Duration

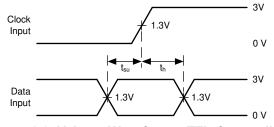
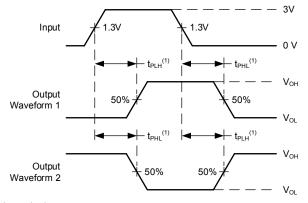


Figure 6-3. Voltage Waveforms, TTL-Compatible CMOS Inputs Setup and Hold Times



(1) The greater between t_{PLH} and t_{PHL} is the same as t_{pd} .

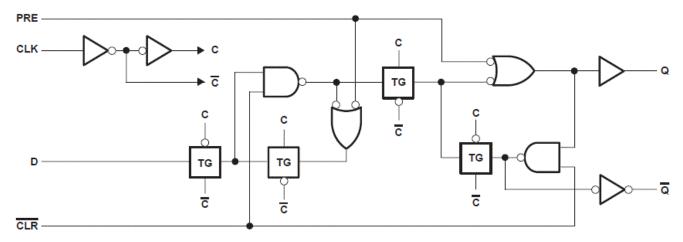
Figure 6-4. Voltage Waveforms, Propagation Delays for TTL-Compatible Inputs

7 Detailed Description

7.1 Overview

The 'HCT74 devices contain two independent D-type positive-edge-triggered flip-flops. A low level at the preset (\overline{PRE}) or clear (\overline{CLR}) inputs sets or resets the outputs, regardless of the levels of the other inputs. When \overline{PRE} and \overline{CLR} are inactive (high), data at the data (D) input meeting the setup time requirements are transferred to the outputs on the positive-going edge of the clock (CLK) pulse. Clock triggering occurs at a voltage level and is not directly related to the rise time of CLK. Following the hold-time interval, data at the D input may be changed without affecting the levels at the outputs.

7.2 Functional Block Diagram



7.3 Device Functional Modes

Table 7-1. Function Table

	INP	OUTPUT			
PRE	CLR	CLK	D	Q	Q
L	Н	X	Х	Н	L
Н	L	Х	Х	L	Н
L	L	Х	Х	H ⁽¹⁾	H ⁽¹⁾
Н	Н	1	Н	Н	L
Н	Н	1	L	L	Н
Н	Н	L	Х	Q_0	Q ₀

(1) This configuration is nonstable; that is, it does not persist when PRE or CLR returns to its inactive (high) level.



8 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

8.1 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the *Recommended Operating Conditions*. Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. A 0.1-µF capacitor is recommended for this device. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. The 0.1-µF and 1-µF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

8.2 Layout

8.2.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices, inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V_{CC}, whichever makes more sense for the logic function or is more convenient.



9 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

9.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

9.2 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

9.3 Trademarks

TI E2E™ is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

9.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

9.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
JM38510/65352B2A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65352B2A
JM38510/65352B2A.A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65352B2A
JM38510/65352BCA	Active	Production	CDIP (J) 14	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65352BCA
JM38510/65352BCA.A	Active	Production	CDIP (J) 14	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65352BCA
JM38510/65352BDA	Active	Production	CFP (W) 14	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65352BDA
JM38510/65352BDA.A	Active	Production	CFP (W) 14	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65352BDA
M38510/65352B2A	Active	Production	LCCC (FK) 20	55 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65352B2A
M38510/65352BCA	Active	Production	CDIP (J) 14	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65352BCA
M38510/65352BDA	Active	Production	CFP (W) 14	25 TUBE	No	SNPB	N/A for Pkg Type	-55 to 125	JM38510/ 65352BDA
SN74HCT74D	Obsolete	Production	SOIC (D) 14	-	-	Call TI	Call TI	-40 to 85	HCT74
SN74HCT74DBR	Active	Production	SSOP (DB) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HT74
SN74HCT74DBR.A	Active	Production	SSOP (DB) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HT74
SN74HCT74DR	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	HCT74
SN74HCT74DR.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT74
SN74HCT74DR.B	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT74
SN74HCT74DRE4	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT74
SN74HCT74DRE4.A	Active	Production	SOIC (D) 14	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT74
SN74HCT74N	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HCT74N
SN74HCT74N.A	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HCT74N
SN74HCT74NE4	Active	Production	PDIP (N) 14	25 TUBE	Yes	NIPDAU	N/A for Pkg Type	-40 to 85	SN74HCT74N
SN74HCT74NSR	Active	Production	SOP (NS) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT74
SN74HCT74NSR.A	Active	Production	SOP (NS) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HCT74



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Orderable part number	Status	Material type	Package Pins	Package qty Carrier	RoHS	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking
	(1)	(2)			(3)	(4)	(5)		(6)
SN74HCT74PW	Obsolete	Production	TSSOP (PW) 14	-	-	Call TI	Call TI	-40 to 85	HT74
SN74HCT74PWR	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	HT74
SN74HCT74PWR.A	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HT74
SN74HCT74PWRG4	Active	Production	TSSOP (PW) 14	2000 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 85	HT74

⁽¹⁾ Status: For more details on status, see our product life cycle.

- (3) RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.
- (4) Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.
- (5) MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.
- (6) Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN54HCT74, SN74HCT74:

Catalog: SN74HCT74

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

PACKAGE OPTION ADDENDUM

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Military: SN54HCT74

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications



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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74HCT74DBR	SSOP	DB	14	2000	330.0	16.4	8.35	6.6	2.4	12.0	16.0	Q1
SN74HCT74DR	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HCT74DRE4	SOIC	D	14	2500	330.0	16.4	6.5	9.0	2.1	8.0	16.0	Q1
SN74HCT74NSR	SOP	NS	14	2000	330.0	16.4	8.1	10.4	2.5	12.0	16.0	Q1
SN74HCT74PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74HCT74PWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74HCT74PWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74HCT74PWRG4	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1



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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74HCT74DBR	SSOP	DB	14	2000	353.0	353.0	32.0
SN74HCT74DR	SOIC	D	14	2500	353.0	353.0	32.0
SN74HCT74DRE4	SOIC	D	14	2500	353.0	353.0	32.0
SN74HCT74NSR	SOP	NS	14	2000	353.0	353.0	32.0
SN74HCT74PWR	TSSOP	PW	14	2000	353.0	353.0	32.0
SN74HCT74PWR	TSSOP	PW	14	2000	353.0	353.0	32.0
SN74HCT74PWRG4	TSSOP	PW	14	2000	353.0	353.0	32.0
SN74HCT74PWRG4	TSSOP	PW	14	2000	356.0	356.0	35.0

PACKAGE MATERIALS INFORMATION

www.ti.com 1-Aug-2025

TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
JM38510/65352B2A	FK	LCCC	20	55	506.98	12.06	2030	NA
JM38510/65352B2A.A	FK	LCCC	20	55	506.98	12.06	2030	NA
JM38510/65352BDA	W	CFP	14	25	506.98	26.16	6220	NA
JM38510/65352BDA.A	W	CFP	14	25	506.98	26.16	6220	NA
M38510/65352B2A	FK	LCCC	20	55	506.98	12.06	2030	NA
M38510/65352BDA	W	CFP	14	25	506.98	26.16	6220	NA
SN74HCT74N	N	PDIP	14	25	506	13.97	11230	4.32
SN74HCT74N	N	PDIP	14	25	506	13.97	11230	4.32
SN74HCT74N.A	N	PDIP	14	25	506	13.97	11230	4.32
SN74HCT74N.A	N	PDIP	14	25	506	13.97	11230	4.32
SN74HCT74NE4	N	PDIP	14	25	506	13.97	11230	4.32
SN74HCT74NE4	N	PDIP	14	25	506	13.97	11230	4.32



SMALL OUTLINE INTEGRATED CIRCUIT



- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm, per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm, per side.
- 5. Reference JEDEC registration MS-012, variation AB.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



MECHANICAL DATA

NS (R-PDSO-G**)

14-PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



W (R-GDFP-F14)

CERAMIC DUAL FLATPACK



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within MIL STD 1835 GDFP1-F14







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
 4. Reference JEDEC registration MO-150.





NOTES: (continued)

- 5. Publication IPC-7351 may have alternate designs.
- 6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 7. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 8. Board assembly site may have different recommendations for stencil design.



8.89 x 8.89, 1.27 mm pitch

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.



CERAMIC DUAL IN LINE PACKAGE



Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4040083-5/G





CERAMIC DUAL IN LINE PACKAGE



- 1. All controlling linear dimensions are in inches. Dimensions in brackets are in millimeters. Any dimension in brackets or parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This package is hermitically sealed with a ceramic lid using glass frit.
- His package is remitted by sealed with a ceramic its using glass mit.
 Index point is provided on cap for terminal identification only and on press ceramic glass frit seal only.
 Falls within MIL-STD-1835 and GDIP1-T14.



CERAMIC DUAL IN LINE PACKAGE



N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.







- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.





NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.





NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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